

SD101AWS-G, SD101BWS-G, SD101CWS-G

Vishay Semiconductors

Small Signal Schottky Diodes



MECHANICAL DATA

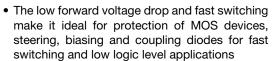
Case: SOD-323

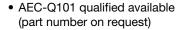
Weight: approx. 4.0 mg
Packaging codes/options:

18/10K per 13" reel (8 mm tape), 10K/box 08/3K per 7" reel (8 mm tape), 15K/box

FEATURES

- For general purpose applications
- The SD101 series is a metal-on-silicon Schottky barrier device which is protected by a PN junction guardring





Base P/N-G3 - green, commercial grade

 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>









PARTS TABLE						
PART	ORDERING CODE	INTERNAL CONSTRUCTION	TYPE MARKING	REMARKS		
SD101AWS-G	SD101AWS-G3-08 or SD101AWS-G3-18	Single diode	SK			
SD101BWS-G	SD101BWS-G3-08 or SD101BWS-G3-18	Single diode	SL	Tape and reel		
CD101CWC C	CD1010MC C2 00 or CD1010MC C2 10	Cinala diada	CM			

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT
		SD101AWS-G	V_{RRM}	60	V
Repetitive peak reverse voltage		SD101BWS-G	V_{RRM}	50	V
		SD101CWS-G	V_{RRM}	40	V
Power dissipation (infinite heatsink) (1)			P _{tot}	150	mW
Forward continuous current			I _F	30	mA
Maximum single cycle surge	10 μs square wave		I _{FSM}	2	Α

Note

⁽¹⁾ Valid provided that electrodes are kept at ambient temperature

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Thermal resistance junction to ambient air (1)		R _{thJA}	650	K/W	
Junction temperature (1)		Tj	125	°C	
Operating temperature range		T _{op}	-55 to +125	°C	
Storage temperature range		T _{stq}	-65 to +150	°C	

Note

⁽¹⁾ Valid provided that electrodes are kept at ambient tamperature

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PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Reverse breakdown voltage	I _R = 10 μA	SD101AWS-G	V _(BR)	60			V
		SD101BWS-G	V _(BR)	50			V
		SD101CWS-G	V _(BR)	40			V
Leakage current	V _R = 50 V	SD101AWS-G	I _R			200	nA
	V _R = 40 V	SD101BWS-G	I _R			200	nA
	V _R = 30 V	SD101CWS-G	I _R			200	nA
	I _F = 1 mA	SD101AWS-G	V _F			410	mV
		SD101BWS-G	V_{F}			400	mV
Forward voltage drap		SD101CWS-G	V _F			390	mV
Forward voltage drop		SD101AWS-G	V _F			1000	mV
	I _F = 15 mA	SD101BWS-G	V_{F}			950	mV
		SD101CWS-G	V _F			900	mV
Junction capacitance	V _R = 0 V, f = 1 MHz	SD101AWS-G	C _D			2.0	ns
		SD101BWS-G	C _D			2.1	ns
		SD101CWS-G	C _D			2.2	ns
Reverse recovery time	$I_F = I_R = 5 \text{ mA},$ recover to 0.1 I_R		t _{rr}			1	ns

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

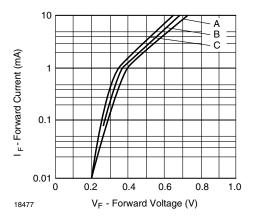


Fig. 1 - Typical Variation of Forward Current vs. Forward Voltage

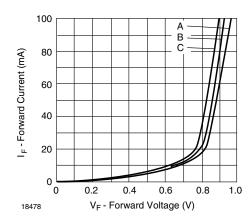


Fig. 2 - Typical Forward Conduction Curve

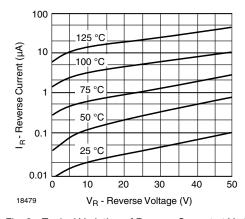


Fig. 3 - Typical Variation of Reverse Current at Various Temperatures

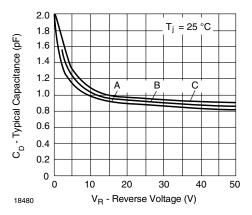


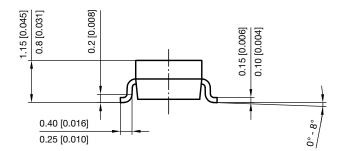
Fig. 4 - Typical Capacitance Curve as a Function of Reverse Voltage

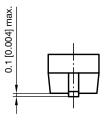


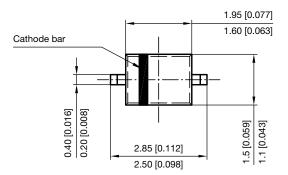
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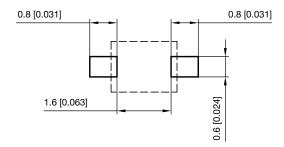
PACKAGE DIMENSIONS in millimeters (inches): SOD-323







Footprint recommendation:



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